## NSN 5962-01-260-3013

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View Online at https://aerobasegroup.com/nsn/5962-01-260-3013 **Body Length:** 1.375 inches **Body Width:** 0.500 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 825.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and ultraviolet erasable and programmable **Inclosure Material:** Ceramic or plastic or metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Current Rating Per Characteristic:** 150.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Tin Voltage Rating And Type Per Characteristic: 0.6 volts power source **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

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